

ERRATA

Erratum: "Current crowding in GaN/InGaN light emitting diodes on insulating substrates" [J. Appl. Phys. 90, 4191 (2001)]

X. Guo and E. F. Schubert^{a)}

Department of Electrical and Computer Engineering, Boston University, 8 Saint Mary's Street, Boston, Massachusetts 02215

[DOI: 10.1063/1.1512721]

Equation (5) of our publication contains a misprint. The correct equation is

$$(\rho_c + \rho_p t_p) J_0 \frac{e}{kT} e^{eV_j/kT} \left[\frac{d^2 V_j}{dx^2} + \frac{e}{kT} \left(\frac{dV_j}{dx} \right)^2 \right] + \frac{d^2 V_j}{dx^2} = \frac{\rho_n}{t_n} J_0 (e^{eV_j/kT} - 1). \quad (5)$$

None of the results or conclusions were affected by this.

^{a)}Electronic mail: schubert@rpi.edu